# Octal D-Type Flip-Flop with 3-State Output

The MC74VHC574 is an advanced high speed CMOS octal flip-flip with 3-state output fabricated with silicon gate CMOS technology. It achieves high speed operation similar to equivalent Bipolar Schottky TTL while maintaining CMOS low power dissipation.

This 8-bit D-type flip-flop is controlled by a clock input and an output enable input. When the output enable input is high, the eight outputs are in a high impedance state.

The internal circuit is composed of three stages, including a buffer output which provides high noise immunity and stable output. The inputs tolerate voltages up to 7 V, allowing the interface of 5 V systems to 3 V systems.

- High Speed:  $f_{max} = 180 \text{ MHz}$  (Typ) at  $V_{CC} = 5 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 4 \mu A$  (Max) at  $T_A = 25^{\circ}C$
- High Noise Immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$
- Power Down Protection Provided on Inputs
- Balanced Propagation Delays
- Designed for 2 V to 5.5 V Operating Range
- Low Noise: V<sub>OLP</sub> = 1.2 V (Max)
- Pin and Function Compatible with Other Standard Logic Families
- Latchup Performance Exceeds 300 mA
- ESD Performance: HBM > 2000 V; Machine Model > 200 V
- Chip Complexity: 266 FETs or 66.5 Equivalent Gates
- These Devices are Pb-Free and are RoHS Compliant



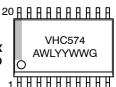
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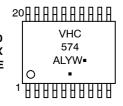
## **MARKING DIAGRAMS**



SOIC-20 DW SUFFIX CASE 751D







VHC574 = Specific Device Code A = Assembly Location

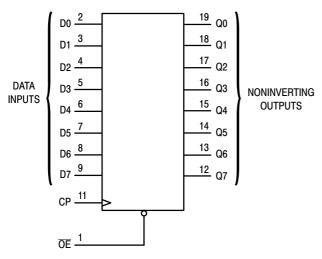
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G or = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

| Device          | Package  | Shipping <sup>†</sup> |
|-----------------|----------|-----------------------|
| MC74VHC574DWR2G | SOIC-20  | 1000 / T&R            |
| MC74VHC574DWG   | SOIC-20  | 38 / Rail             |
| MC74VHC574DTR2G | TSSOP-20 | 2500 / T&R            |
| MC74VHC574DTG   | TSSOP-20 | 75 / Rail             |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.



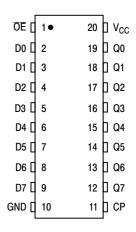


Figure 1. LOGIC DIAGRAM

Figure 2. PIN ASSIGNMENT

# **FUNCTION TABLE**

|    | INPUTS      | OUTPUT |                |
|----|-------------|--------|----------------|
| ŌĒ | СР          | D      | Q              |
| L  | ۲ /         | Н      | H              |
| L  | L, H,∖<br>X | X      | No Change<br>Z |

### **MAXIMUM RATINGS\***

| Symbol           | Paramete                                 | r                                | Value                          | Unit |
|------------------|--|----------------------------------|--------------------------------|------|
| V <sub>CC</sub>  | DC Supply Voltage                        |                                  | - 0.5 to + 7.0                 | V    |
| V <sub>in</sub>  | DC Input Voltage                         |                                  | - 0.5 to + 7.0                 | V    |
| V <sub>out</sub> | DC Output Voltage                        |                                  | - 0.5 to V <sub>CC</sub> + 0.5 | V    |
| I <sub>IK</sub>  | Input Diode Current                      | - 20                             | mA                             |      |
| I <sub>OK</sub>  | Output Diode Current                     |                                  | ± 20                           | mA   |
| l <sub>out</sub> | DC Output Current, per Pin               |                                  | ± 25                           | mA   |
| I <sub>CC</sub>  | DC Supply Current, V <sub>CC</sub> and G | ND Pins                          | ± 75                           | mA   |
| P <sub>D</sub>   | Power Dissipation in Still Air,          | SOIC Packages†<br>TSSOP Package† | 500<br>450                     | mW   |
| T <sub>stg</sub> | Storage Temperature                      |                                  | - 65 to + 150                  | °C   |

<sup>\*</sup> Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

# RECOMMENDED OPERATING CONDITIONS

| Symbol                          | Parameter  | Min  | Max       | Unit |
|---------------------------------|--|------|-----------|------|
| V <sub>CC</sub>                 | DC Supply Voltage  | 2.0  | 5.5       | V    |
| V <sub>in</sub>                 | DC Input Voltage   | 0    | 5.5       | V    |
| V <sub>out</sub>                | DC Output Voltage  | 0    | $V_{CC}$  | V    |
| T <sub>A</sub>                  | Operating Temperature  | - 40 | + 85      | °C   |
| t <sub>r</sub> , t <sub>f</sub> | Input Rise and Fall Time $ V_{CC} = 3.3 V_{CC} = 5.0 V_{CC} \label{eq:VCC} $ | 0    | 100<br>20 | ns/V |

### DC ELECTRICAL CHARACTERISTICS

|                 |                                      |  | V <sub>CC</sub>      |                               | T <sub>A</sub> = 25°C | ;                             | $T_A = -40$                   | 0 to 85°C                     |      |
|-----------------|--------------------------------------|--|----------------------|-------------------------------|-----------------------|-------------------------------|-------------------------------|-------------------------------|------|
| Symbol          | Parameter                            | Test Conditions  | V                    | Min                           | Тур                   | Max                           | Min                           | Max                           | Unit |
| V <sub>IH</sub> | Minimum High-Level<br>Input Voltage  |  | 2.0<br>3.0 to<br>5.5 | 1.50<br>V <sub>CC</sub> x 0.7 |                       |                               | 1.50<br>V <sub>CC</sub> x 0.7 |                               | V    |
| V <sub>IL</sub> | Maximum Low-Level Input Voltage      |  | 2.0<br>3.0 to<br>5.5 |                               |                       | 0.50<br>V <sub>CC</sub> x 0.3 |                               | 0.50<br>V <sub>CC</sub> x 0.3 | V    |
| V <sub>OH</sub> | Minimum High-Level<br>Output Voltage | $V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OH} = -50 \mu A$              | 2.0<br>3.0<br>4.5    | 1.9<br>2.9<br>4.4             | 2.0<br>3.0<br>4.5     |                               | 1.9<br>2.9<br>4.4             |                               | V    |
|                 |                                      | $V_{in} = V_{IH} \text{ or } V_{IL} \\ I_{OH} = -4mA \\ I_{OH} = -8mA$ | 3.0<br>4.5           | 2.58<br>3.94                  |                       |                               | 2.48<br>3.80                  |                               |      |
| V <sub>OL</sub> | Maximum Low-Level<br>Output Voltage  | $V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \mu A$               | 2.0<br>3.0<br>4.5    |                               | 0.0<br>0.0<br>0.0     | 0.1<br>0.1<br>0.1             |                               | 0.1<br>0.1<br>0.1             | V    |
|                 |                                      | $V_{in} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 4mA$ $I_{OL} = 8mA$     | 3.0<br>4.5           |                               |                       | 0.36<br>0.36                  |                               | 0.44<br>0.44                  |      |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range GND  $\leq$  ( $V_{in}$  or  $V_{out}$ )  $\leq$   $V_{CC}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

<sup>†</sup>Derating — SOIC Packages: – 7 mW/°C from 65° to 125°C TSSOP Package: – 6.1 mW/°C from 65° to 125°C

### DC ELECTRICAL CHARACTERISTICS

|                 |   |   | v <sub>cc</sub> | ,   | T <sub>A</sub> = 25°C |        | T <sub>A</sub> = - 40 | 0 to 85°C |      |
|-----------------|---|---|-----------------|-----|-----------------------|--------|-----------------------|-----------|------|
| Symbol          | Parameter                                 | Test Conditions   | v               | Min | Тур                   | Max    | Min                   | Max       | Unit |
| l <sub>in</sub> | Maximum Input<br>Leakage Current          | V <sub>in</sub> = 5.5V or GND   | 0 to 5.5        |     |                       | ± 0.1  |                       | ± 1.0     | μА   |
| I <sub>OZ</sub> | Maximum<br>Three-State Leakage<br>Current | V <sub>in</sub> = V <sub>IL</sub> or V <sub>IH</sub><br>V <sub>out</sub> = V <sub>CC</sub> or GND | 5.5             |     |                       | ± 0.25 |                       | ± 2.5     | μА   |
| Icc             | Maximum Quiescent<br>Supply Current       | V <sub>in</sub> = V <sub>CC</sub> or GND  | 5.5             |     |                       | 4.0    |                       | 40.0      | μА   |

## AC ELECTRICAL CHARACTERISTICS (Input $t_f = t_f = 3.0$ ns)

|  |  |  |  |           | T <sub>A</sub> = 25°C |              | T <sub>A</sub> = - 4 | 0 to 85°C    |      |
|--|--|--|--|-----------|-----------------------|--------------|----------------------|--------------|------|
| Symbol                                   | Parameter  | Test Condi   | tions  | Min       | Тур                   | Max          | Min                  | Max          | Unit |
| f <sub>max</sub>                         | Maximum Clock Frequency<br>(50% Duty Cycle)                                  | $V_{CC} = 3.3 \pm 0.3 V$   | $C_L = 15pF$<br>$C_L = 50pF$                   | 80<br>50  | 125<br>75             | _            | 65<br>45             | _<br>_       | ns   |
|  |  | $V_{CC} = 5.0 \pm 0.5 V$   | $C_L = 15pF$<br>$C_L = 50pF$                   | 130<br>85 | 180<br>115            | _            | 110<br>75            | _<br>_       |      |
| t <sub>PLH</sub> ,<br>t <sub>PHL</sub>   | Maximum Propagation Delay,<br>CP to Q  | $V_{CC} = 3.3 \pm 0.3$   | $C_L = 15pF$<br>$C_L = 50pF$                   |           | 8.5<br>11.0           | 13.2<br>16.7 | 1.0<br>1.0           | 15.5<br>19.0 | ns   |
|  |  | $V_{CC} = 5.0 \pm 0.5 V$   | $C_L = 15pF$<br>$C_L = 50pF$                   |           | 5.6<br>7.1            | 8.6<br>10.6  | 1.0<br>1.0           | 10.0<br>12.0 | -    |
| t <sub>PZL</sub> ,<br>t <sub>PZH</sub>   | Output Enable Time,<br>OE to Q   | $\begin{aligned} V_{CC} &= 3.3 \pm 0.3 V \\ R_L &= 1 k \Omega \end{aligned}$ | C <sub>L</sub> = 15pF<br>C <sub>L</sub> = 50pF | _         | 8.2<br>10.7           | 12.8<br>16.3 | 1.0<br>1.0           | 15.0<br>18.5 | ns   |
|  |  | $V_{CC} = 5.0 \pm 0.5V$ $R_L = 1k\Omega$                                     | C <sub>L</sub> = 15pF<br>C <sub>L</sub> = 50pF | _         | 5.9<br>7.4            | 9.0<br>11.0  | 1.0<br>1.0           | 10.5<br>12.5 |      |
| t <sub>PLZ</sub> ,<br>t <sub>PHZ</sub>   | Output Disable Time,<br>OE to Q  | $\begin{aligned} V_{CC} &= 3.3 \pm 0.3 V \\ R_L &= 1 k \Omega \end{aligned}$ | C <sub>L</sub> = 50pF                          | _         | 11.0                  | 15.0         | 1.0                  | 17.0         | ns   |
|  |  | $V_{CC} = 5.0 \pm 0.5V$ $R_L = 1k\Omega$                                     | C <sub>L</sub> = 50pF                          | _         | 7.1                   | 10.1         | 1.0                  | 11.5         | -    |
| t <sub>OSLH</sub> ,<br>t <sub>OSHL</sub> | Output to Output Skew  | V <sub>CC</sub> = 3.3 ± 0.3V<br>(Note 1)                                     | C <sub>L</sub> = 50pF                          | _         | _                     | 1.5          | _                    | 1.5          | ns   |
|  |  | V <sub>CC</sub> = 5.0 ± 0.5V<br>(Note 1)                                     | C <sub>L</sub> = 50pF                          | _         | _                     | 1.0          | _                    | 1.0          | ns   |
| C <sub>in</sub>                          | Maximum Input Capacitance  |  |  | _         | 4                     | 10           | _                    | 10           | pF   |
| C <sub>out</sub>                         | Maximum Three-State Output<br>Capacitance, Output in<br>High-Impedance State |  |  | _         | 6                     | _            | _                    | _            | pF   |

|          |  | Typical @ 25°C, V <sub>CC</sub> = 5.0V |    |
|----------|--|--|----|
| $C_{PD}$ | Power Dissipation Capacitance (Note 2) | 28                                     | pF |

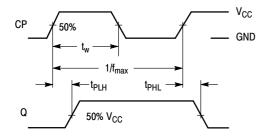
Parameter guaranteed by design. t<sub>OSLH</sub> = |t<sub>PLHm</sub> - t<sub>PLHn</sub>|, t<sub>OSHL</sub> = |t<sub>PHLm</sub> - t<sub>PHLn</sub>|.
 C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>/8 (per flip-flop). C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

# NOISE CHARACTERISTICS (Input $t_r = t_f = 3.0$ ns, $C_L = 50$ pF, $V_{CC} = 5.0$ V)

|                  |  | T <sub>A</sub> = 25°C |       |      |
|------------------|--|-----------------------|-------|------|
| Symbol           | Parameter                                    | Тур                   | Max   | Unit |
| V <sub>OLP</sub> | Quiet Output Maximum Dynamic V <sub>OL</sub> | 0.9                   | 1.2   | V    |
| V <sub>OLV</sub> | Quiet Output Minimum Dynamic V <sub>OL</sub> | - 0.9                 | - 1.2 | V    |
| V <sub>IHD</sub> | Minimum High Level Dynamic Input Voltage     | _                     | 3.5   | V    |
| V <sub>ILD</sub> | Maximum Low Level Dynamic Input Voltage      | _                     | 1.5   | V    |

# **TIMING REQUIREMENTS** (Input $t_r = t_f = 3.0 \text{ns}$ )

|                 |                             |  | T <sub>A</sub> = | 25°C       | T <sub>A</sub> = - 40<br>to 85°C |      |
|-----------------|-----------------------------|--|------------------|------------|----------------------------------|------|
| Symbol          | Parameter                   | Test Conditions  | Тур              | Limit      | Limit                            | Unit |
| t <sub>su</sub> | Minimum Setup Time, D to CP | $V_{CC} = 3.3 \pm 0.3 \text{ V}$<br>$V_{CC} = 5.0 \pm 0.5 \text{ V}$ |                  | 3.5<br>3.5 | 3.5<br>3.5                       | ns   |
| t <sub>h</sub>  | Minimum Hold Time, CP to D  | $V_{CC} = 3.3 \pm 0.3 \text{ V}$<br>$V_{CC} = 5.0 \pm 0.5 \text{ V}$ |                  | 1.5<br>1.5 | 1.5<br>1.5                       | ns   |
| t <sub>w</sub>  | Minimum Pulse Width, CP     | $V_{CC} = 3.3 \pm 0.3 \text{ V}$<br>$V_{CC} = 5.0 \pm 0.5 \text{ V}$ | _<br>_           | 5.0<br>5.0 | 5.5<br>5.0                       | ns   |



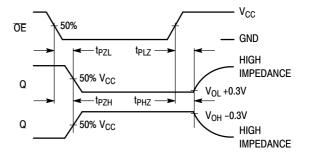
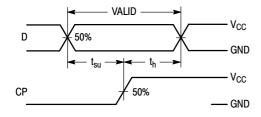
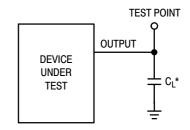


Figure 3. Switching Waveforms





\*Includes all probe and jig capacitance

Figure 4.

Figure 5.

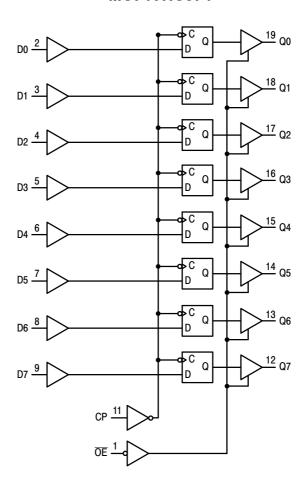
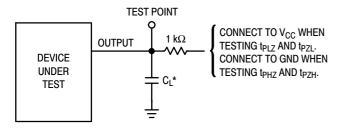


Figure 6. Expanded Logic Diagram



\*Includes all probe and jig capacitance

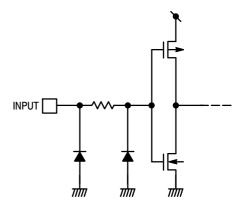
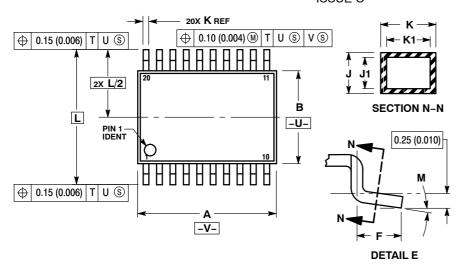


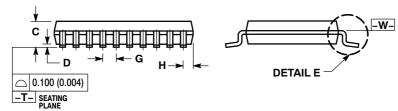
Figure 7. Test Circuit

Figure 8. INPUT EQUIVALENT CIRCUIT

### PACKAGE DIMENSIONS

### TSSOP-20 CASE 948E-02 ISSUE C



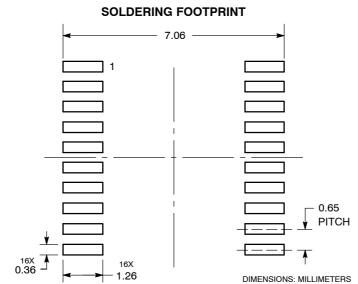


#### NOTES:

- DTES:

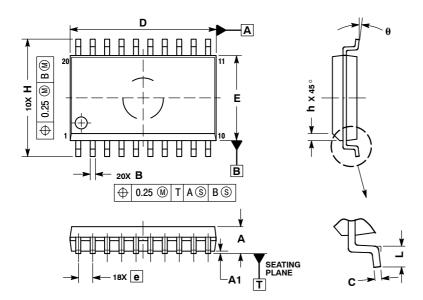
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
  4. DIMENSION B DOES NOT INCLUDE INTERI EAD EI ASH OR PROTRUSION.
- 4. DIMENSION B DUES NOT INCLUDE
  INTERLEAD FLASH OR PROTRUSION.
  INTERLEAD FLASH OR PROTRUSION
  SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
  5. DIMENSION K DOES NOT INCLUDE
  DAMBAR PROTRUSION. ALLOWABLE
  DAMBAR PROTRUSION SHALL BE 0.08
- (0.003) TOTAL IN EXCESS OF THE K
  DIMENSION AT MAXIMUM MATERIAL
- 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

|     |        |        | AINE -VV  |       |
|-----|--------|--------|-----------|-------|
|     | MILLIN | IETERS | INC       | HES   |
| DIM | MIN    | MAX    | MIN       | MAX   |
| Α   | 6.40   | 6.60   | 0.252     | 0.260 |
| В   | 4.30   | 4.50   | 0.169     | 0.177 |
| С   |        | 1.20   |           | 0.047 |
| D   | 0.05   | 0.15   | 0.002     | 0.006 |
| F   | 0.50   | 0.75   | 0.020     | 0.030 |
| G   | 0.65   | BSC    | 0.026 BSC |       |
| Н   | 0.27   | 0.37   | 0.011     | 0.015 |
| J   | 0.09   | 0.20   | 0.004     | 0.008 |
| J1  | 0.09   | 0.16   | 0.004     | 0.006 |
| K   | 0.19   | 0.30   | 0.007     | 0.012 |
| K1  | 0.19   | 0.25   | 0.007     | 0.010 |
| L   | 6.40   |        | 0.252     |       |
| M   | 0°     | 8°     | 0°        | 8°    |



### PACKAGE DIMENSIONS

### SOIC-20 **DW SUFFIX** CASE 751D-05 **ISSUE G**



#### NOTES:

- DIMENSIONS ARE IN MILLIMETERS.
  INTERPRET DIMENSIONS AND TOLERANCES
  PER ASME Y14.5M, 1994.
  DIMENSIONS D AND E DO NOT INCLUDE MOLD
- PROTRUSION.

  MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR
- PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

|     | MILLIMETERS |       |  |  |  |
|-----|-------------|-------|--|--|--|
| DIM | MIN         | MAX   |  |  |  |
| Α   | 2.35        | 2.65  |  |  |  |
| A1  | 0.10        | 0.25  |  |  |  |
| В   | 0.35        | 0.49  |  |  |  |
| С   | 0.23        | 0.32  |  |  |  |
| D   | 12.65       | 12.95 |  |  |  |
| Е   | 7.40        | 7.60  |  |  |  |
| е   | 1.27        | BSC   |  |  |  |
| Н   | 10.05       | 10.55 |  |  |  |
| h   | 0.25        | 0.75  |  |  |  |
| L   | 0.50        | 0.90  |  |  |  |
| θ   | 0°          | 7 °   |  |  |  |

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